

# FAN6756AHL — mWSaver™ PWM Controller

## Features

- Single-Ended Topologies, such as Flyback
- mWSaver™ Technology
  - Achieves Low No-Load Power Consumption: < 30 mW at 230 V<sub>AC</sub> (EMI Filter Loss Included)
  - Eliminates X Capacitor Discharge Resistor Loss with AX-CAP® Technology
  - Linearly Decreases Switching Frequency to 23 kHz
  - Burst Mode Operation at Light-Load Condition
  - Impedance Modulation in Deep Burst Mode
  - Low Operating Current (450 µA) in Deep Burst Mode
  - 500 V High-Voltage JFET Startup Circuit Eliminates Startup Resistor Loss
- Highly Integrated with Rich Features
  - Proprietary Frequency Hopping to Reduce EMI
  - High-Voltage Sampling to Detect Input Voltage
  - Peak-Current-Mode Control with Slope Compensation
  - Cycle-by-Cycle Current Limiting with Line Compensation
  - Leading-Edge Blanking (LEB)
  - Built-In 5.5 ms Soft-Start
- Advanced Protections
  - Brown-In/Brownout Recovery
  - Internal Overload / Open-Loop Protection (OLP)
  - V<sub>DD</sub> Under-Voltage Lockout (UVLO)
  - V<sub>DD</sub> Over-Voltage Protection (V<sub>DD</sub> OVP)
  - Over-Temperature Protection (OTP)

## Description

The FAN6756AHL is a next-generation Green Mode PWM controller with innovative mWSaver™ technology, which dramatically reduces standby and no-load power consumption, enabling compliance with worldwide Standby Mode efficiency guidelines.

An innovative AX-CAP® method minimizes losses in the EMI filter stage by eliminating the X-cap discharge resistors while meeting IEC61010-1 safety requirements. Deep Burst Mode clamps feedback voltage and modulates feedback impedance with an impedance modulator during Burst Mode operation, which forces the system to operate in a Deep Burst Mode with minimum switching losses.

Protections ensure safe operation of power system in various abnormal conditions. A proprietary frequency-hopping function decreases EMI emission. Built-in synchronized slope compensation allows more stable Peak-Current-Mode control over a wide range of input voltage and load conditions. The proprietary internal line compensation ensures constant output power limit over entire universal line voltage range.

Requiring a minimum number of external components, FAN6756AHL provides a basic platform that is well suited for cost-effective flyback converter designs that require extremely low standby power consumption.

## Applications

Flyback power supplies that demand extremely low standby power consumption, such as:

- Adapters for Notebooks, Printers, Game Consoles
- Open-Frame SMPS for LCD TVs, LCD Monitors, Printers

## Ordering Information

| Part Number  | Protections <sup>(1)</sup> |     |     |     | Operating Temperature Range | Package                            | Packing Method |
|--------------|----------------------------|-----|-----|-----|-----------------------------|------------------------------------|----------------|
|              | OLP                        | OCP | OVP | OTP |                             |                                    |                |
| FAN6756AHLMX | L                          | L   | L   | L   | -40 to +105°C               | 8-Pin, Small Outline Package (SOP) | Tape & Reel    |

### Note:

1. L = Latch Mode protection.

## Application Diagram

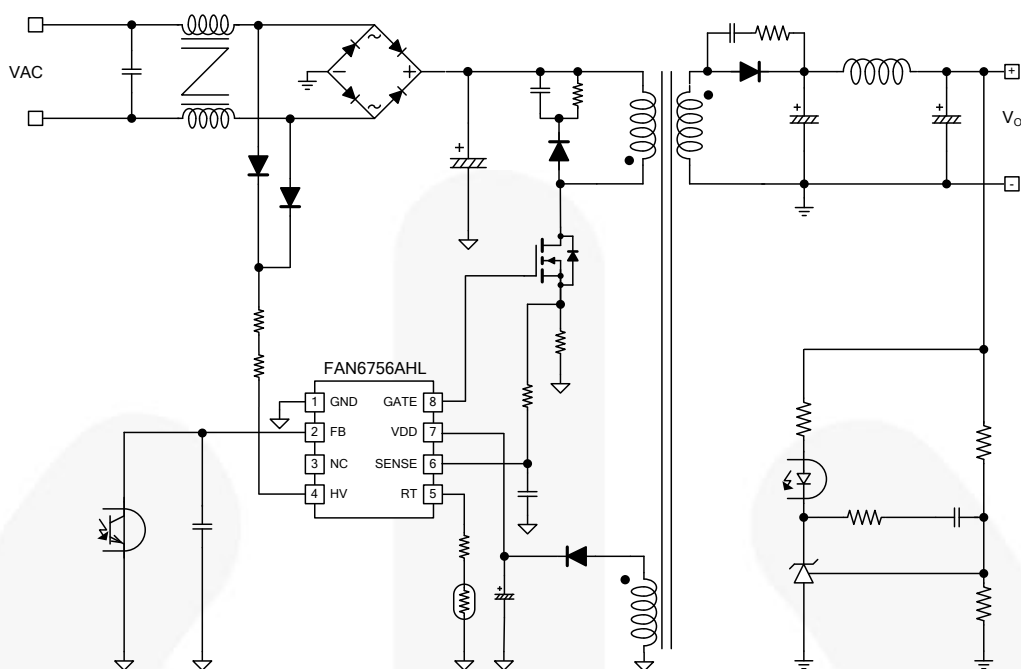


Figure 1. Typical Application

## Internal Block Diagram

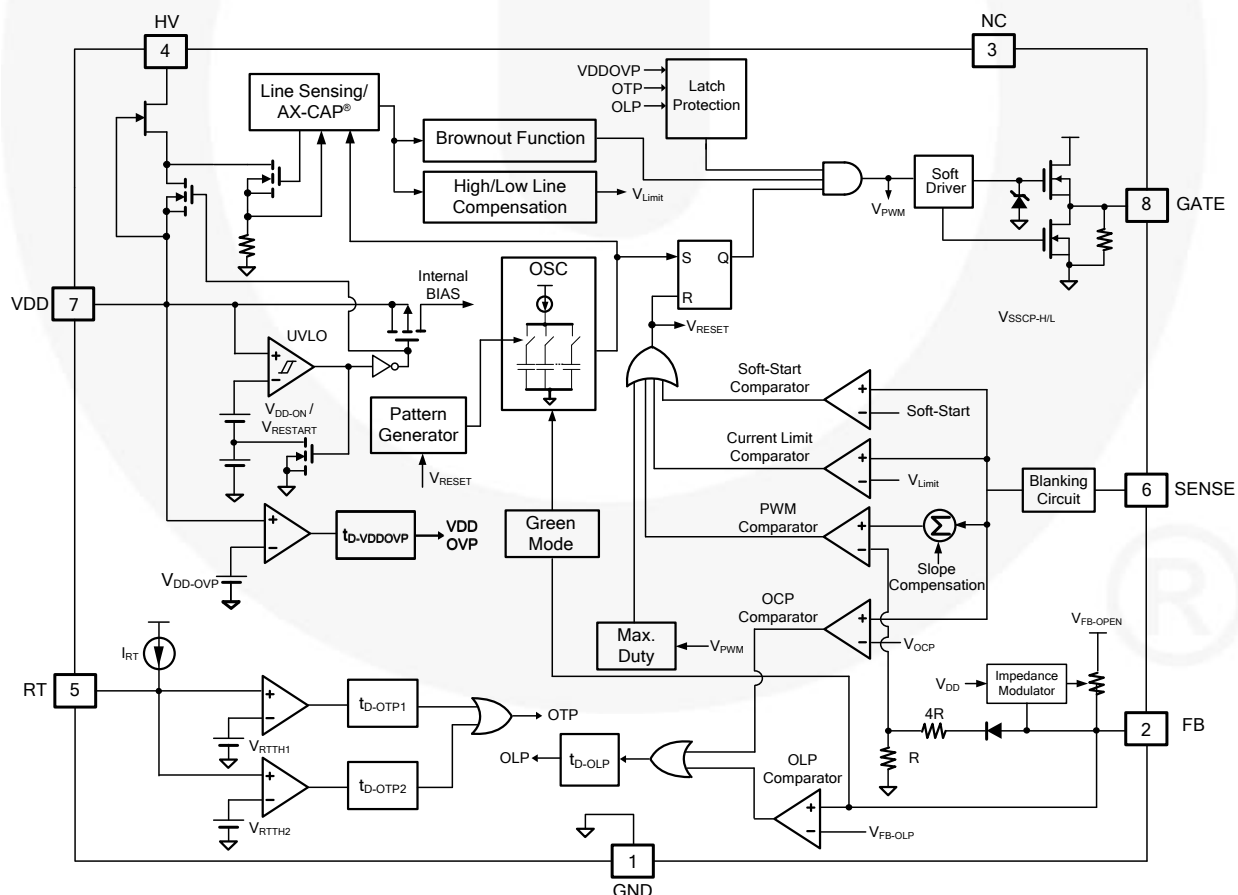
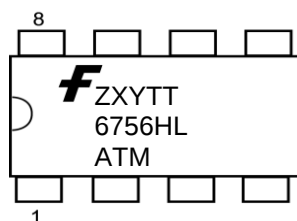


Figure 2. Functional Block Diagram

## Marking Information



Z – Plant Code  
 X – 1-Digit Year Code  
 Y – 1-Digit Week Code  
 TT – 2-Digit Die Run Code  
 T – Package Type (M=SOP)  
 A – Stands for FAN6756AHL  
 M – Manufacture Flow Code

Figure 3. Top Mark

## Pin Configuration

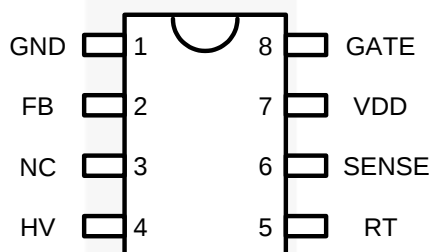


Figure 4. Pin Configuration (Top View)

## Pin Definitions

| Pin # | Name  | Description                                                                                                                                                                                                                                                                                                                                                                                                                                                                        |
|-------|-------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 1     | GND   | Ground. Placing a 0.1 $\mu$ F decoupling capacitor between VDD and GND is recommended.                                                                                                                                                                                                                                                                                                                                                                                             |
| 2     | FB    | Feedback. The output voltage feedback information from the external compensation circuit is fed into this pin. The PWM duty cycle is determined by comparing the FB signal with the current-sense signal from the SENSE pin.                                                                                                                                                                                                                                                       |
| 3     | NC    | No connection.                                                                                                                                                                                                                                                                                                                                                                                                                                                                     |
| 4     | HV    | High-Voltage Startup. The HV pin is typically connected to the AC line input through two external diodes and one resistor ( $R_{HV}$ ). This pin is used, not only to charge the $V_{DD}$ capacitor during startup, but also to sense the line voltage. The line voltage information is used for brownout protection and power-limit line compensation. This pin is also used to intelligently discharge the EMI filter capacitor when removal of the AC line voltage is detected. |
| 5     | RT    | Over-Temperature Protection. An external NTC thermistor is connected from this pin to GND. If the voltage of the RT pin drops below the threshold voltage, the controller latches off the PWM. The RT pin also provides external latch protection. If the RT pin is not connected to the NTC resistor for over-temperature protection, it is recommended to place a 100 k $\Omega$ resistor to ground to prevent from noise interference.                                          |
| 6     | SENSE | Current Sense. The sensed voltage is used for Peak-Current-Mode control and cycle-by-cycle current limiting.                                                                                                                                                                                                                                                                                                                                                                       |
| 7     | VDD   | Power Supply of IC. Typically a hold-up capacitor connects from this pin to ground. A rectifier diode, in series with the transformer auxiliary winding, connects to this pin to supply bias during normal operation.                                                                                                                                                                                                                                                              |
| 8     | GATE  | Gate Drive Output. The totem-pole output driver for the power MOSFET; internally clamped to $V_{GATE-CLAMP}$ .                                                                                                                                                                                                                                                                                                                                                                     |

## Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

| Symbol             | Parameter                                           |                                       | Min. | Max. | Unit |
|--------------------|-----------------------------------------------------|---------------------------------------|------|------|------|
| V <sub>DD</sub>    | DC Supply Voltage <sup>(2,3)</sup>                  |                                       |      | 30   | V    |
| V <sub>FB</sub>    | FB Pin Input Voltage                                |                                       | -0.3 | 7.0  | V    |
| V <sub>SENSE</sub> | SENSE Pin Input Voltage                             |                                       | -0.3 | 7.0  | V    |
| V <sub>RT</sub>    | RT Pin Input Voltage                                |                                       | -0.3 | 7.0  | V    |
| V <sub>HV</sub>    | HV Pin Input Voltage                                |                                       |      | 500  | V    |
| P <sub>D</sub>     | Power Dissipation (T <sub>A</sub> < 50°C)           |                                       |      | 400  | mW   |
| Θ <sub>JA</sub>    | Thermal Resistance (Junction-to-Air)                |                                       |      | 150  | °C/W |
| T <sub>J</sub>     | Operating Junction Temperature                      |                                       | -40  | +125 | °C   |
| T <sub>STG</sub>   | Storage Temperature Range                           |                                       | -55  | +150 | °C   |
| T <sub>L</sub>     | Lead Temperature (Wave Soldering or IR, 10 Seconds) |                                       |      | +260 | °C   |
| ESD                | Human Body Model, JEDEC:JESD22-A114                 | All Pins Except HV Pin <sup>(4)</sup> |      | 6    | kV   |
|                    | Charged Device Model, JEDEC:JESD22-C101             | All Pins Except HV Pin <sup>(4)</sup> |      | 2    |      |

### Notes:

- All voltage values, except differential voltages, are given with respect to the network ground terminal.
- Stresses beyond those listed under Absolute Maximum Rating may cause permanent damage to the device.
- ESD level on HV pin is CDM=1250 V and HBM=500 V.

## Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. We does not recommend exceeding them or designing to Absolute Maximum Ratings.

| Symbol          | Parameter            | Min. | Typ. | Max. | Unit |
|-----------------|----------------------|------|------|------|------|
| R <sub>HV</sub> | Resistance on HV Pin | 150  | 200  | 250  | kΩ   |

## Electrical Characteristics

$V_{DD}=15\text{ V}$  and  $T_J=T_A=25^\circ\text{C}$  unless otherwise noted.

| Symbol                        | Parameter                                                                     | Condition                                                                     | Min.                       | Typ.                 | Max.                 | Unit          |
|-------------------------------|-------------------------------------------------------------------------------|-------------------------------------------------------------------------------|----------------------------|----------------------|----------------------|---------------|
| <b>V<sub>DD</sub> Section</b> |                                                                               |                                                                               |                            |                      |                      |               |
| $V_{DD-ON}$                   | Threshold Voltage to Startup                                                  | $V_{DD}$ Rising                                                               | 16                         | 17                   | 18                   | V             |
| $V_{UVLO}$                    | Threshold Voltage to Stop Switching in Normal Mode                            | $V_{DD}$ Falling                                                              | 5.5                        | 6.5                  | 7.5                  | V             |
| $V_{RESTART}$                 | Threshold Voltage to Enable HV Startup to Charge $V_{DD}$ in Normal Mode      | $V_{DD}$ Falling                                                              | 4.2                        | 4.7                  | 5.2                  | V             |
| $V_{DD-OFF}$                  | Threshold Voltage to Stop Operating in Protection Mode                        | $V_{DD}$ Falling                                                              | 10                         | 11                   | 12                   | V             |
| $V_{DD-OLP}$                  | Threshold Voltage to Enable HV Startup to Charge $V_{DD}$ in Protection Mode  | $V_{DD}$ Falling                                                              | 6                          | 7                    | 8                    | V             |
| $V_{DD-LH}$                   | Threshold Voltage to Release Latch Mode                                       | $V_{DD}$ Falling                                                              | 3.5                        | 4.0                  | 4.5                  | V             |
| $V_{DD-AC}$                   | Minimum Voltage of VDD Pin for Enabling Brown-in                              |                                                                               | $V_{UVLO} + 2.5$           | $V_{UVLO} + 3$       | $V_{UVLO} + 3.5$     | V             |
| $I_{DD-ST}$                   | Startup Current                                                               | $V_{DD}=V_{DD-ON} - 0.16\text{ V}$                                            |                            |                      | 30                   | $\mu\text{A}$ |
| $I_{DD-OP1}$                  | Supply Current in PWM Operation                                               | $V_{DD}=15\text{ V}$ , $V_{FB} = 3\text{ V}$ Gate Open                        |                            |                      | 2                    | mA            |
| $I_{DD-OP2}$                  | Supply Current when PWM Stops                                                 | $V_{DD}=15\text{ V}$ , $V_{FB} < 1.4\text{ V}$ , in Deep Burst Mode, Gate Off |                            | 450                  |                      | $\mu\text{A}$ |
| $I_{DD-OLP}$                  | Internal Sink Current, $V_{DD-OLP} < V_{DD} < V_{DD-OFF}$ , Protection Mode   | $V_{DD}=V_{DD-OLP} + 0.1\text{ V}$                                            | 160                        | 210                  | 260                  | $\mu\text{A}$ |
| $I_{LH}$                      | Internal Sink Current $V_{DD} < V_{DD-OLP}$ , Latch-Protection Mode           | $V_{DD}=5\text{ V}$                                                           | 40                         |                      |                      | $\mu\text{A}$ |
| $V_{DD-OVP}$                  | Threshold Voltage for $V_{DD}$ Over-Voltage Protection                        |                                                                               | 23.5                       | 24.5                 | 25.5                 | V             |
| $t_{D-VDDOVP}$                | $V_{DD}$ Over-Voltage Protection Debounce Time                                |                                                                               | 110                        | 205                  | 300                  | $\mu\text{s}$ |
| $V_{DD-ZFBR}$                 | $V_{DD}$ Threshold Voltage for FB Pin Impedance Modulation in Deep Burst Mode |                                                                               |                            | 7                    |                      | V             |
| <b>HV Section</b>             |                                                                               |                                                                               |                            |                      |                      |               |
| $I_{HV}$                      | Inherent Current Limit of HV Pin                                              | $V_{AC}=90\text{ V}$ ( $V_{DC}=120\text{ V}$ ), $V_{DD}=0\text{ V}$           | 2.0                        | 3.5                  | 5.0                  | mA            |
| $V_{AC-OFF}$                  | Threshold Voltage for Brownout                                                | $R_{HV}=200\text{ k}\Omega$ to HV Pin                                         | 90                         | 100                  | 110                  | V             |
| $V_{AC-ON}$                   | Threshold Voltage for Brown-In                                                | $R_{HV}=200\text{ k}\Omega$ to HV Pin                                         | 100                        | 110                  | 120                  | V             |
| $\Delta V_{AC}$               | $V_{AC-ON} - V_{AC-OFF}$                                                      | $R_{HV}=200\text{ k}\Omega$ to HV Pin                                         | 8                          | 12                   | 16                   | V             |
| $t_{D-AC-OFF}$                | Debounce Time for Brownout                                                    |                                                                               | 540                        | 710                  | 880                  | ms            |
| $V_{HV-DIS}$                  | X-Cap. Discharge Threshold                                                    | $R_{HV}=200\text{ k}\Omega$ to HV Pin                                         | $V_{DC}^{(5)} \times 0.45$ | $V_{DC} \times 0.51$ | $V_{DC} \times 0.56$ | V             |
| $t_{D-HV-DIS}$                | Debounce Time for Triggering X-Cap. Discharge                                 |                                                                               | 75                         | 115                  | 155                  | ms            |
| $t_{HV-DIS}$                  | Discharge Time when X-Cap. Discharge is Triggered                             |                                                                               | 360                        | 510                  | 660                  | ms            |

Continued on the following page...

## Electrical Characteristics

$V_{DD}=15\text{ V}$  and  $T_J=T_A=25^\circ\text{C}$  unless otherwise noted.

| Symbol                        | Parameter                                                      | Condition                                                                             | Min.       | Typ.       | Max.       | Unit       |
|-------------------------------|----------------------------------------------------------------|---------------------------------------------------------------------------------------|------------|------------|------------|------------|
| <b>Oscillator Section</b>     |                                                                |                                                                                       |            |            |            |            |
| $f_{OSC}$                     | Maximum Switching Frequency                                    | Center Frequency                                                                      | 94         | 100        | 106        | kHz        |
|                               |                                                                | Hopping Range ( $V_{FB}>V_{FB-N}$ )                                                   | $\pm 5.45$ | $\pm 6.70$ | $\pm 7.95$ |            |
| $t_{HOP}$                     | Hopping Period                                                 | $V_{FB}>V_{FB-G}$                                                                     | 5.12       | 6.40       | 7.68       | ms         |
| $f_{OSC-G}$                   | Green-Mode Switching Frequency                                 | Center Frequency ( $V_{FB}<V_{FB-N}$ )                                                | 20         | 23         | 26         | kHz        |
|                               |                                                                | Hopping range <sup>(6)</sup> (Increase $V_{FB}$ from $V_{FB-G}$ until hopping starts) | $\pm 1.25$ | $\pm 1.50$ | $\pm 1.75$ |            |
| $f_{DV}$                      | Frequency Variation vs. $V_{DD}$ Deviation                     | $V_{DD}=11\text{ V}$ to $22\text{ V}$                                                 |            |            | 5          | %          |
| $f_{DT}$                      | Frequency Variation vs. Temperature Deviation                  | $T_A=-40$ to $105^\circ\text{C}$                                                      |            |            | 5          | %          |
| <b>Feedback Input Section</b> |                                                                |                                                                                       |            |            |            |            |
| $A_V$                         | Feedback Voltage to Current-Sense Attenuation                  |                                                                                       | 1/5.5      | 1/5.0      | 1/4.5      | V/V        |
| $Z_{FB}$                      | Regular FB Internal Pull-High Impedance                        |                                                                                       |            | 8.5        |            | k $\Omega$ |
| $V_{FB-OPEN}$                 | FB Internal Bias Voltage                                       | FB Pin Open                                                                           | 5.2        | 5.4        | 5.6        | V          |
| $V_{FB-OLP}$                  | Threshold Voltage for OLP                                      |                                                                                       | 4.2        | 4.5        | 4.8        | V          |
| $t_{D-OLP}$                   | Delay for OLP and OCP                                          |                                                                                       | 33.0       | 43.5       | 54.0       | ms         |
| $V_{FB-N}$                    | Threshold Voltage for Maximum Switching Frequency              |                                                                                       | 2.1        | 2.3        | 2.5        | V          |
| $V_{FB-G}$                    | Threshold Voltage for Minimum Switching Frequency              |                                                                                       | 1.6        | 1.8        | 2.0        | V          |
| $V_{FB-ZDCR}$                 | FB Threshold Voltage for Zero-Duty Recovery                    |                                                                                       | 1.4        | 1.6        | 1.8        | V          |
| $V_{FB-ZDC}$                  | FB Threshold Voltage for Zero-Duty                             |                                                                                       | 1.3        | 1.5        | 1.7        | V          |
| $V_{FB-ZDCR-DBM}$             | FB Threshold Voltage for Zero-Duty Recovery in Deep Burst Mode | $V_{DD}=V_{UVLO}+0.3\text{ V}$                                                        | 2.0        | 2.2        | 2.4        | V          |
| $V_{FB-ZDC-DBM}$              | FB Threshold Voltage for Zero-Duty in Deep Burst Mode          |                                                                                       | 1.8        | 2.0        | 2.2        | V          |
| $t_{DBM}$                     | Condition of Entering Deep Burst Mode                          | $V_{FB}<V_{FB-ZDC}$ Repeats 3 Times Continuously                                      |            | 7.5        |            | ms         |
| $t_{D-DBM}$                   | Delay time of Entering Deep Burst Mode                         |                                                                                       | 600        |            |            | ms         |
| $V_{FB-RECOVER}$              | Threshold Voltage for Leaving Deep Burst Mode Immediately      |                                                                                       |            | 0.9        |            | V          |

Continued on the following page...

## Electrical Characteristics

$V_{DD}=15\text{ V}$  and  $T_J=T_A=25^\circ\text{C}$  unless otherwise noted.

| Symbol                                           | Parameter                                                                           | Condition                                                       | Min.  | Typ.         | Max.  | Unit             |
|--------------------------------------------------|-------------------------------------------------------------------------------------|-----------------------------------------------------------------|-------|--------------|-------|------------------|
| <b>Current-Sense Section</b>                     |                                                                                     |                                                                 |       |              |       |                  |
| $t_{PD}$                                         | Propagation Delay to Output                                                         |                                                                 |       | 100          | 175   | ns               |
| $t_{LEB}$                                        | Leading-Edge Blanking Time                                                          | Soft-Start                                                      | 100   | 132          | 164   | ns               |
|                                                  |                                                                                     | Steady State                                                    | 200   | 265          | 330   | ns               |
| $V_{LIMIT-L}$                                    | Current Limit at Low Line ( $V_{AC-RMS}=86\text{ V}$ )                              | $V_{DC}=122\text{ V}$ , $R_{HV}=200\text{ k}\Omega$ to HV Pin   | 0.66  | 0.70         | 0.74  | V                |
| $V_{LIMIT-H}$                                    | Current Limit at High Line ( $V_{AC-RMS}=259\text{ V}$ )                            | $V_{DC}=366\text{ V}$ , $R_{HV}=200\text{ k}\Omega$ to HV Pin   | 0.55  | 0.59         | 0.63  | V                |
| $V_{OCP-L}$                                      | Threshold Voltage for OCP at Low Line ( $V_{AC-RMS}=86\text{ V}$ )                  | $V_{DC}=122\text{ V}$ , $R_{HV}=200\text{ k}\Omega$ to HV Pin   | 0.43  | 0.46         | 0.49  | V                |
| $V_{OCP-H}$                                      | Threshold Voltage for OCP at High Line ( $V_{AC-RMS}=259\text{ V}$ )                | $V_{DC}=366\text{ V}$ , $R_{HV}=200\text{ k}\Omega$ to HV Pin   | 0.33  | 0.36         | 0.39  | V                |
| $t_{SS}$                                         | Soft-Start Time                                                                     | Startup                                                         | 4.5   | 5.5          | 6.5   | ms               |
| <b>GATE Section</b>                              |                                                                                     |                                                                 |       |              |       |                  |
| $DCY_{MAX}$                                      | Maximum Duty Cycle                                                                  |                                                                 | 75.0  | 82.5         | 90.0  | %                |
| $V_{GATE-L}$                                     | Gate Low Voltage                                                                    | $V_{DD}=15\text{ V}$ , $I_O=50\text{ mA}$                       |       |              | 1.5   | V                |
| $V_{GATE-H}$                                     | Gate High Voltage                                                                   | $V_{DD}=12\text{ V}$ , $I_O=50\text{ mA}$                       | 8     |              |       | V                |
| $t_r$                                            | Gate Rising Time                                                                    | $V_{DD}=15\text{ V}$ , $C_L=1\text{ nF}$                        |       | 110          |       | ns               |
| $t_f$                                            | Gate Falling Time                                                                   | $V_{DD}=15\text{ V}$ , $C_L=1\text{ nF}$                        |       | 40           |       | ns               |
| $V_{GATE-CLAMP}$                                 | Gate Output Clamping Voltage                                                        | $V_{DD}=22\text{ V}$                                            | 11.0  | 14.5         | 18.0  | V                |
| <b>RT Section</b>                                |                                                                                     |                                                                 |       |              |       |                  |
| $I_{RT}$                                         | Output Current of RT Pin                                                            |                                                                 |       | 100          |       | $\mu\text{A}$    |
| $V_{RTTH1}$                                      | Threshold Voltage for Latch Protection (Generally Used for External OTP Triggering) | $V_{RTTH2} < V_{RT} < V_{RTTH1}$ , Latch Off After $t_{D-OTP1}$ | 1.000 | 1.035        | 1.070 | V                |
| $V_{RTTH2}$                                      | The Second Threshold Voltage for Latch Protection                                   | $V_{RTTH2} < 0.7\text{ V}$ , Latch Off After $t_{D-OTP2}$       | 0.65  | 0.70         | 0.75  | V                |
| $R_{OTP}$                                        | The Value of $V_{RTTH1}/I_{RT}$                                                     |                                                                 | 9.66  | 10.50        | 11.34 | $\text{k}\Omega$ |
| $t_{D-OTP1}$                                     | Debounce Time for the First Latch Protection Triggering                             | $V_{RTTH2} < V_{RT} < V_{RTTH1}$                                | 11.0  | 14.5         | 18.0  | ms               |
| $t_{D-OTP2}$                                     | Debounce Time for the Second Latch Protection Triggering                            | $V_{RT} < V_{RTTH2}$                                            | 110   | 185          | 260   | $\mu\text{s}$    |
| <b>Over-Temperature Protection Section (OTP)</b> |                                                                                     |                                                                 |       |              |       |                  |
| $T_{OTP}$                                        | Protection Junction Temperature <sup>(6,7)</sup>                                    |                                                                 |       | +135         |       | $^\circ\text{C}$ |
| $T_{RESTART}$                                    | Restart Junction Temperature <sup>(6)</sup>                                         |                                                                 |       | $T_{OTP}-25$ |       | $^\circ\text{C}$ |

### Notes:

- $V_{DC}$  is  $V_{AC} \times \sqrt{2}$ .
- Guaranteed by design.
- When activated, the GATE output is stopped until junction temperature is below  $T_{RESTART}$ .

## Typical Performance Characteristics

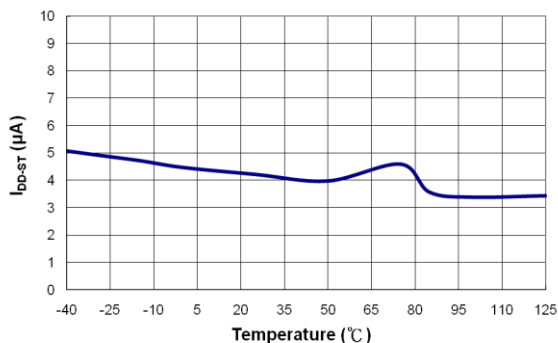


Figure 5. Startup Current ( $I_{DD-ST}$ ) vs. Temperature

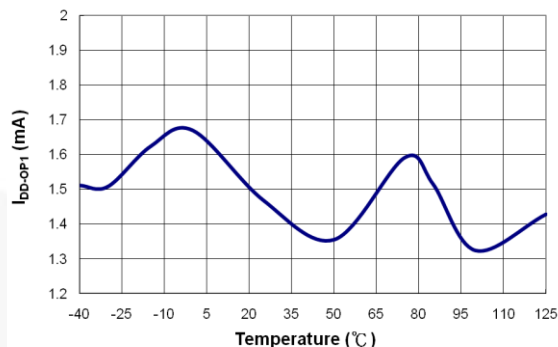


Figure 6. Operation Supply Current ( $I_{DD-OP1}$ ) vs. Temperature

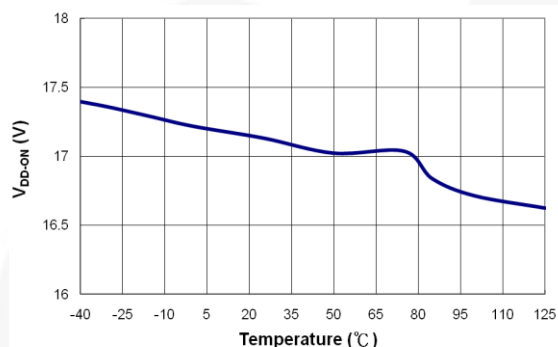


Figure 7. Startup Threshold Voltage ( $V_{DD-ON}$ ) vs. Temperature

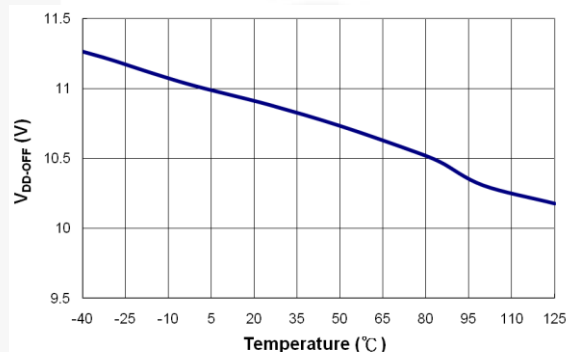


Figure 8. Minimum Operating Voltage under Protection Mode ( $V_{DD-OFF}$ ) vs. Temperature

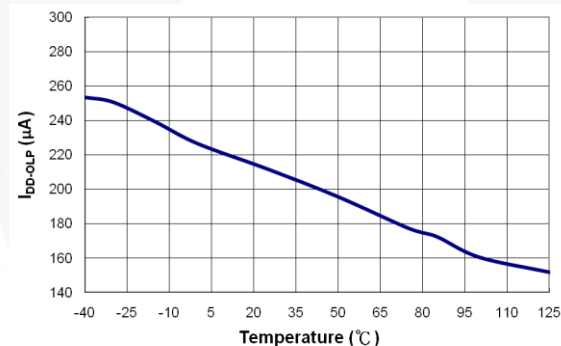


Figure 9. Off-State Internal Sink Current under Protection Mode ( $I_{DD-OLP}$ ) vs. Temperature

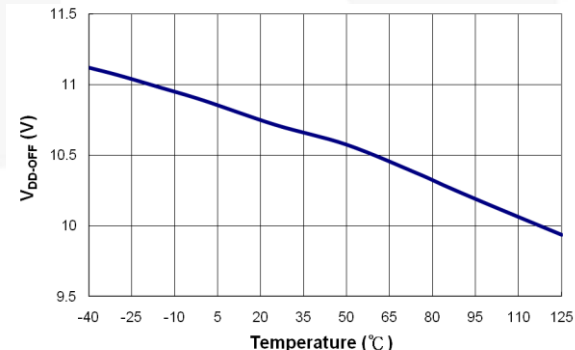


Figure 10. Minimum Operating Voltage ( $V_{UVLO}$ ) vs. Temperature

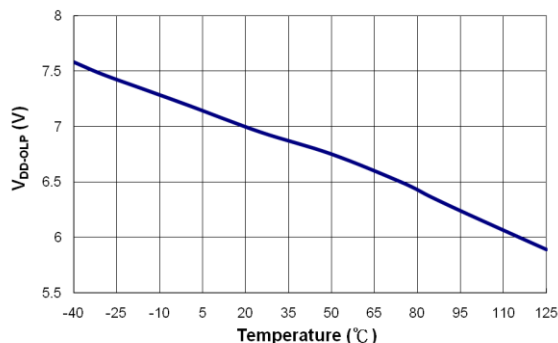


Figure 11. Threshold Voltage to Enable HV Startup in Protection Mode ( $V_{DD-OLP}$ ) vs. Temperature

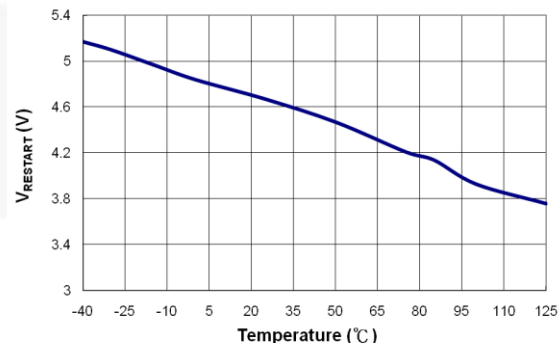
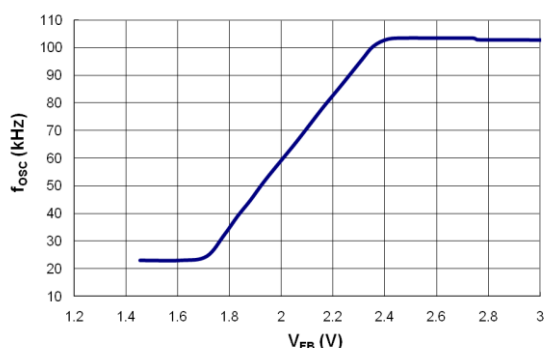
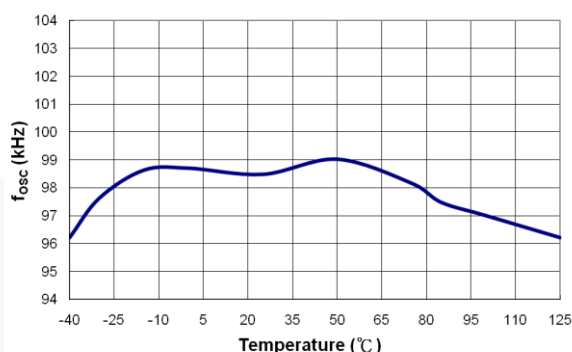
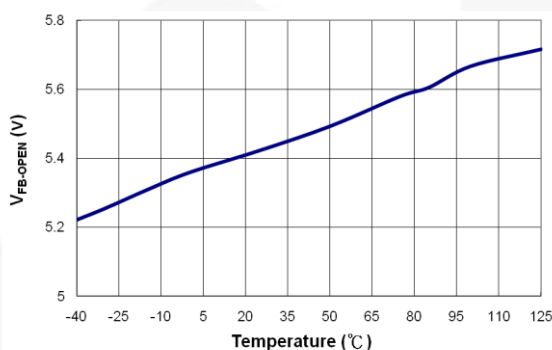
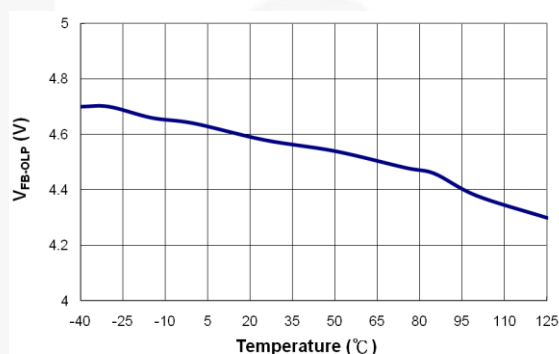
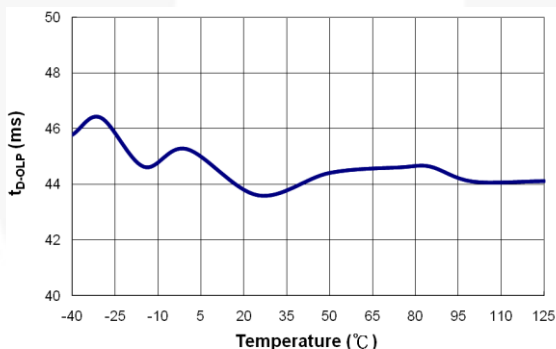
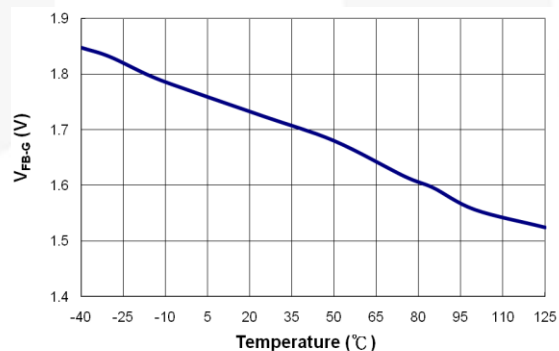
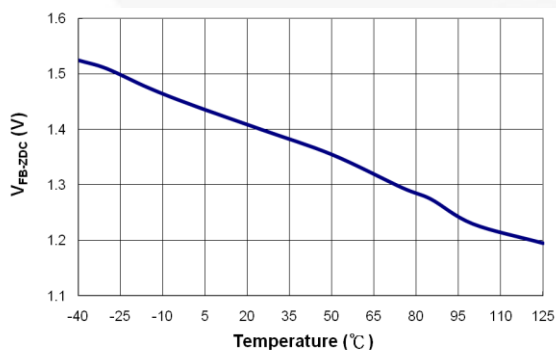
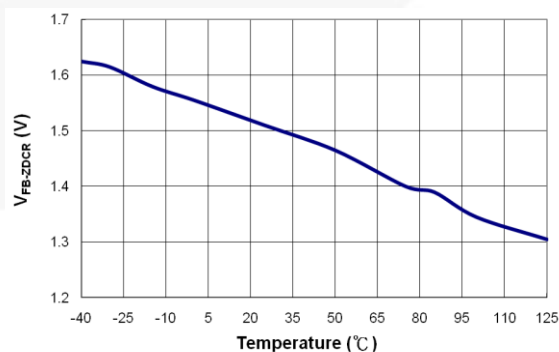
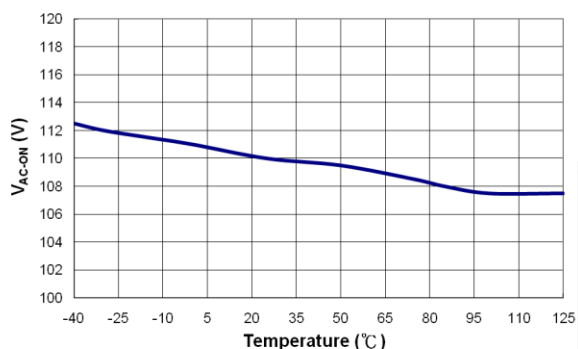
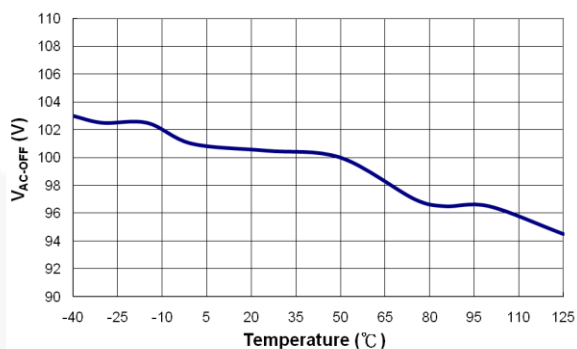
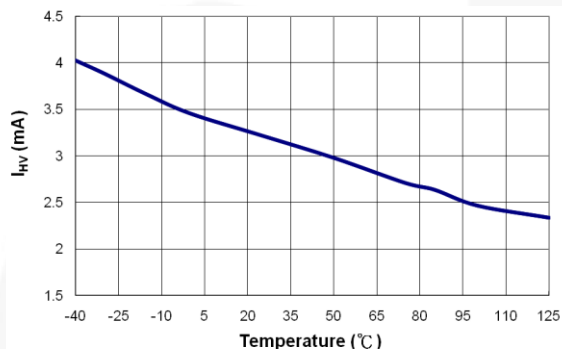
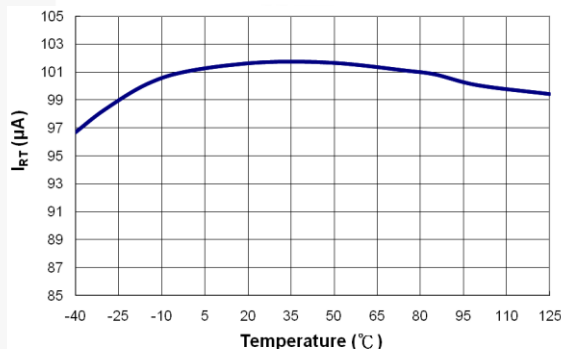
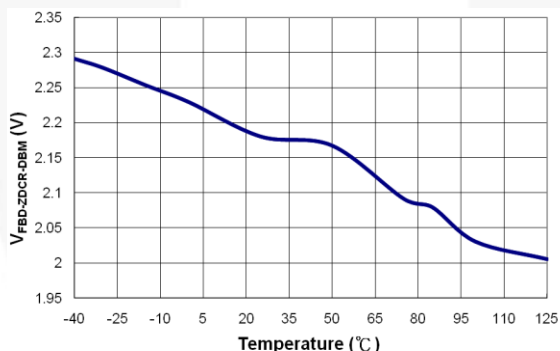
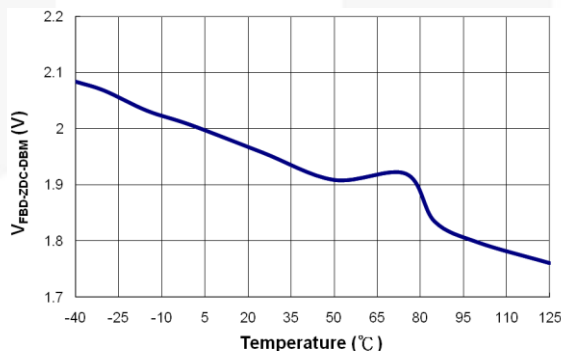


Figure 12. Threshold Voltage to Enable HV Startup to Charge  $V_{DD}$  in Normal Mode ( $V_{RESTART}$ ) vs. Temperature

## Typical Performance Characteristics (Continued)

Figure 13. PWM Switching Frequency vs. Feedback Voltage ( $V_{FB}$ )Figure 14. Maximum Switching Frequency ( $f_{osc}$ ) vs. TemperatureFigure 15. FB Pin Internal Bias Voltage ( $V_{FB-OPEN}$ ) vs. TemperatureFigure 16. Open-Loop Protection Triggering Level ( $V_{FB-OLP}$ ) vs. TemperatureFigure 17. Delay Time for Open-Loop Protection ( $t_{D-OLP}$ ) vs. TemperatureFigure 18. Open-Loop Protection Triggering Level ( $V_{FB-G}$ ) vs. TemperatureFigure 19. Open-Loop Protection Triggering Level ( $V_{FB-ZDC}$ ) vs. TemperatureFigure 20. Open-Loop Protection Triggering Level ( $V_{FB-ZDCR}$ ) vs. Temperature

## Typical Performance Characteristics (Continued)

Figure 21. Brown-in (V<sub>AC-ON</sub>) vs. TemperatureFigure 22. Brownout (V<sub>AC-OFF</sub>) vs. TemperatureFigure 23. Inherent Current Limit of HV-Pin (I<sub>HV</sub>) vs. TemperatureFigure 24. Output Current from RT Pin (I<sub>RT</sub>) vs. TemperatureFigure 25. FB Threshold Voltage for Zero-Duty Recovery in Deep Burst Mode (V<sub>FB-ZDCR-DBM</sub>) vs. TemperatureFigure 26. FB Threshold Voltage for Zero-Duty in Deep Burst Mode (V<sub>FB-ZDC-DBM</sub>) vs. Temperature

## Functional Description

### Current Mode Control

FAN6756AHL employs Peak-Current-Mode control, as shown in Figure 27. An opto-coupler (such as the H11A817A) and a shunt regulator (such as the KA431) are typically used to implement the feedback network. Comparing the feedback voltage with the voltage across the  $R_{sense}$  resistor makes it possible to control the switching duty cycle. Slope compensation stabilizes the current loop and prevents sub-harmonic oscillation.

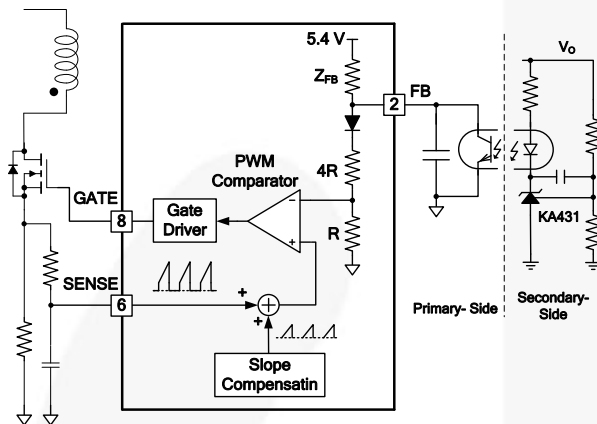


Figure 27. Current-Mode Control Circuit Diagram

### Leading-Edge Blanking (LEB)

Each time the power MOSFET is switched on, a turn-on spike occurs on the sense resistor. To avoid premature termination of the switching pulse, a leading-edge blanking time,  $t_{LEB}$ , is introduced. During this blanking period, the current-limit comparator is disabled and cannot switch off the gate driver.

## mWSaver™ Technology

### Green-Mode

FAN6756AHL modulates the PWM frequency as a function of the FB voltage to improve the medium- and light-load efficiency, as shown in Figure 28. Since the output power is proportional to the FB voltage in Current-Mode control, switching frequency decreases as load decreases. In heavy-load conditions, the maximum switching frequency is fixed at 100 kHz. Once  $V_{FB}$  decreases below  $V_{FB-N}$  (2.3 V), the PWM frequency starts linearly decreasing from 100 kHz to 23 kHz to reduce switching losses. As  $V_{FB}$  drops to  $V_{FB-G}$  (1.8 V), where switching frequency is decreased to 23 kHz, the switching frequency is fixed to avoid acoustic noise.

When  $V_{FB}$  falls below  $V_{FB-ZDC}$  (1.5 V) as load decreases further, the FAN6756AHL enters Burst Mode where PWM switching is disabled. Then the output voltage starts to drop, causing the feedback voltage to rise. Once  $V_{FB}$  rises above  $V_{FB-ZDCR}$  (1.6 V), switching resumes. Burst Mode alternately enables and disables switching, thereby reducing switching loss for lower power consumption, as shown in Figure 29.

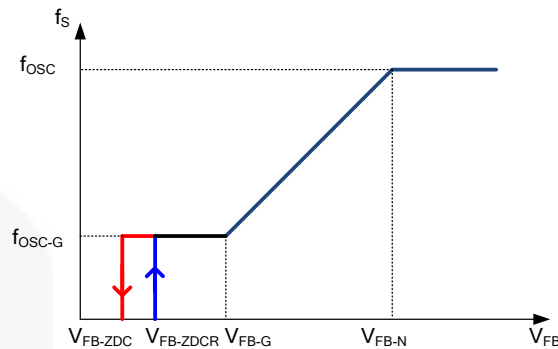


Figure 28.  $V_{FB}$  vs. PWM Frequency

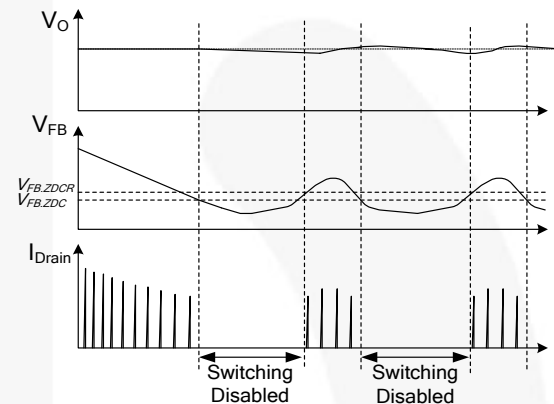


Figure 29. Burst Switching in Green Mode

### Deep Burst Mode & Feedback Impedance Switching

Deep Burst Mode minimizes power consumption at extremely light-load or no-load conditions where, not only the switching loss, but also power consumption of FAN6756AHL itself, are reduced further than in Green Mode. Deep Burst Mode is initiated when the non-switching state of burst switching in Green Mode persists longer than  $t_{DBM}$  (7.5 ms) for three consecutive burst switches (as shown in Figure 30). To prevent entering Deep Burst Mode during dynamic load change, there is  $t_{D-DBM}$  (>600 ms) delay. If there are more than 112 consecutive switching pulses during the  $t_{D-DBM}$  delay, FAN6756AHL does not go into Deep Burst Mode.

Once FAN6756AHL enters Deep Burst Mode, the feedback impedance,  $Z_{FB}$ , is modulated by the impedance modulator, as shown in Figure 31. When  $V_{FB}$  is under a threshold level, the impedance modulator clamps  $V_{FB}$  and disables switching. When  $V_{DD}$  drops to  $V_{DD-ZFBR}$  (7 V, which is 0.5 V higher than  $V_{UVLO}$ ), the impedance modulator controls  $Z_{FB}$ , allowing  $V_{FB}$  to rise and resume switching operation. As shown in Figure 32, by clamping  $V_{FB}$  to disable switching while modulating  $Z_{FB}$  to enable switching, the system is forced into Deep Burst Mode to reduce switching loss.

Deep Burst Mode maintains  $V_{DD}$  as low as possible to minimize power consumption. When FAN6756AHL enters Deep Burst Mode, several blocks are disabled and operation current is reduced from  $I_{DD-OP1}$  to  $I_{DD-OP2}$ .

The feedback voltage thresholds to enter and exit Burst Mode change from  $V_{FB-ZDC}$  (1.5 V) and  $V_{FB-ZDCR}$  (1.6 V) to  $V_{FB-ZDC-DBM}$  (2 V) and  $V_{FB-ZDCR-DBM}$  (2.2 V) in Deep Burst Mode. This reduces the switching loss more by increasing the energy delivered to the load per switching operation, which eventually reduces the total switching for a given load condition.

FAN6756AHL exits Deep Burst Mode after more than 112 consecutive switching pulses in Deep Burst Mode. Once FAN6756AHL exits Deep Burst Mode, the feedback impedance is modulated to 8.5 k $\Omega$  to keep original loop response. FAN6756AHL also exits Deep Burst Mode when the opto-coupler transistor current is virtually zero and  $V_{FB}$  rises above  $V_{FB-RECOVER}$  (0.9 V) while switching is suspended.

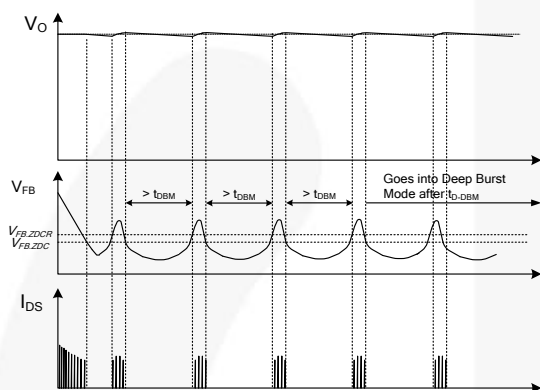


Figure 30. Entering Deep Burst Mode

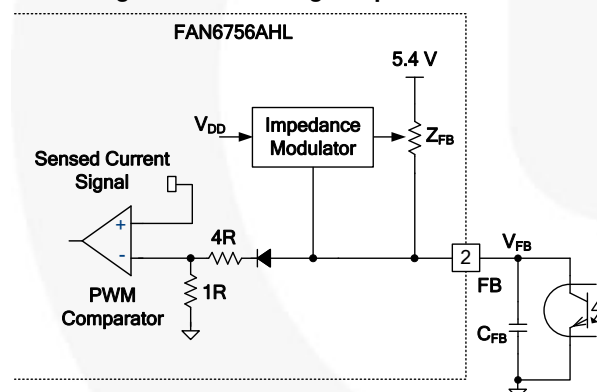


Figure 31. Feedback Impedance Modulation

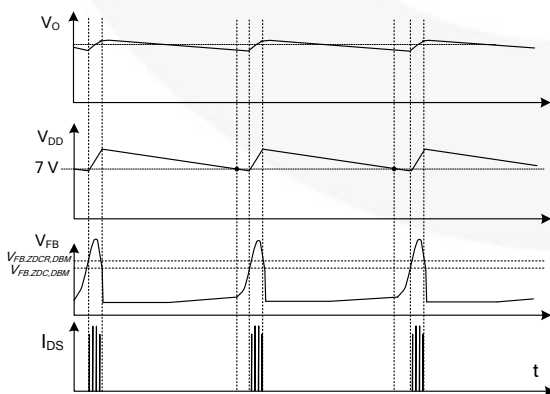


Figure 32. Deep Burst Mode Operation

### High-Voltage Startup and Line Sensing

The HV pin is typically connected to the AC line input through two external diodes and one resistor ( $R_{HV}$ ), as shown in Figure 33. When AC line voltage is applied, the  $V_{DD}$  hold-up capacitor is charged by the line voltage through the diodes and resistor. After  $V_{DD}$  voltage reaches the turn-on threshold voltage ( $V_{DD-ON}$ ), the startup circuit charging the  $V_{DD}$  capacitor is switched off and  $V_{DD}$  is supplied by the auxiliary winding of the transformer. Once FAN6756AHL starts, it continues operating until  $V_{DD}$  drops below 6.5 V ( $V_{UVLO}$ ). IC startup time with a given AC line input voltage is given as:

$$t_{STARTUP} = R_{HV} \cdot C_{DD} \cdot \ln \frac{V_{AC-IN} \cdot \frac{2\sqrt{2}}{\pi}}{V_{AC-IN} \cdot \frac{2\sqrt{2}}{\pi} - V_{DD-ON}} \quad (1)$$

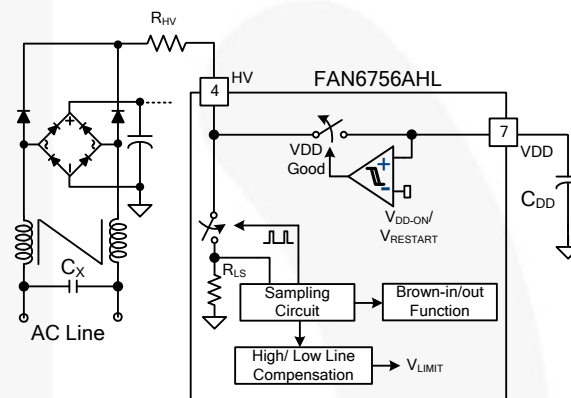


Figure 33. Startup Circuit

The HV pin detects the AC line voltage using a switched voltage divider that consists of external resistor ( $R_{HV}$ ) and internal resistor ( $R_{LS}$ ), as shown in Figure 33. The internal line-sensing circuit detects line voltage using a sampling circuit and peak-detection circuit. Since the voltage divider causes power consumption when it is switched on, the switching is driven by a signal with a very narrow pulse width to minimize power loss. The sampling frequency is adaptively changed according to the load condition to minimize power consumption in light-load condition.

Based on the detected line voltage, brown-in and brownout thresholds are determined as:

$$V_{BROWN-IN} (RMS) = \frac{R_{HV}}{200k} \cdot \frac{V_{AC-ON}}{\sqrt{2}} \quad (2)$$

$$V_{BROWNOUT} (RMS) = \frac{R_{HV}}{200k} \cdot \frac{V_{AC-OFF}}{\sqrt{2}} \quad (3)$$

Since the internal resistor ( $R_{LS}=1.6$  k $\Omega$ ) of the voltage divider is much smaller than  $R_{HV}$ , the thresholds are given as a function of  $R_{HV}$ .

#### Note:

- $V_{DD}$  must be larger than  $V_{DD-AC}$  to start, even though the sensed line voltage satisfies Equation (2), as shown in Figure 34.

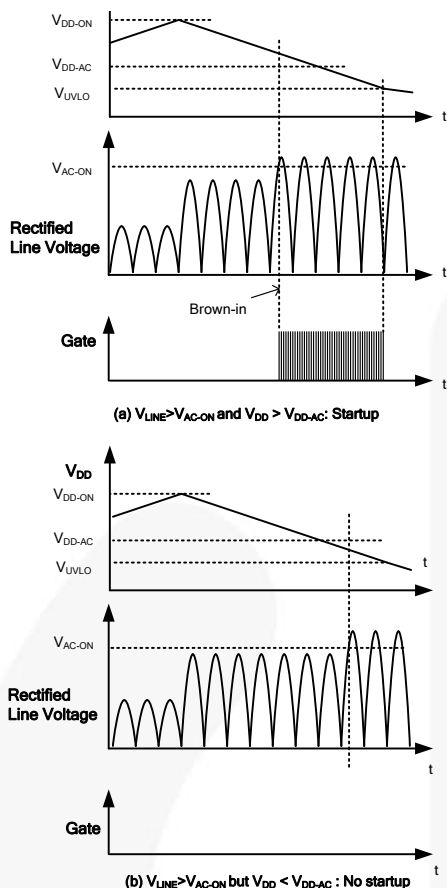


Figure 34. Timing Diagram for Brown-in Function

#### AX-CAP® Discharge

The EMI filter in the front end of the switched-mode power supply (SMPS) typically includes a capacitor across the AC line connector. Most of the safety regulations, such as UL 1950 and IEC61010-1, require the capacitor be discharged to a safe level within a given time when the AC plug is abruptly removed from its receptacle. Typically, discharge resistors across the capacitor are used to ensure that capacitor is discharged naturally, which introduces power loss as long as it is connected to the receptacle.

Innovative AX-CAP® technology intelligently discharges the filter capacitor only when the power supply is unplugged from the power outlet. Since the AX-CAP discharge circuit is disabled in normal operation, the power loss in the EMI filter is virtually removed.

#### High / Low Line Compensation for Constant Power Limit

FAN6756AHL has pulse-by-pulse current limit, as shown in Figure 35, which limits the maximum input power with a given input voltage. If the output consumes beyond this maximum power, the output voltage drops, triggering overload protection.

As shown in Figure 35, based on the line voltage,  $V_{LINE}^{PK}$ , the high/low line compensation block adjusts the current limit level,  $V_{LIMIT}$ , defined as:

$$V_{LIMIT} = \frac{V_{LIMIT,L} - V_{LIMIT,H}}{2} \cdot \frac{R_{LS}}{R_{HV}} \cdot V_{LINE}^{PK} + \frac{3 \cdot V_{LIMIT,L} - V_{LIMIT,H}}{2} \quad (4)$$

To maintain the constant output power limit regardless of line voltage, the cycle-by-cycle current limit level,  $V_{LIMIT}$ , decreases as line voltage increases (as shown in Figure 35). The current limit level is proportional to the  $R_{HV}$  resistor value and the power limit can be tuned using the  $R_{HV}$  resistor.

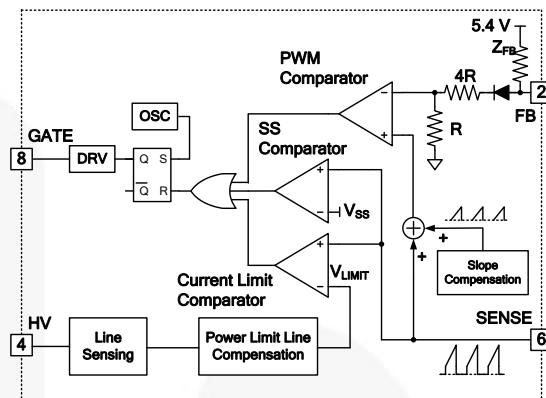


Figure 35. Pulse-by-Pulse Current Limit Circuit

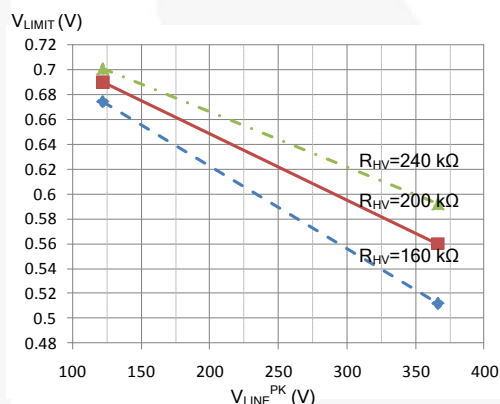


Figure 36. Current Limit vs. Line Voltage

#### Soft-Start

An internal soft-start circuit progressively increases the pulse-by-pulse current limit level of MOSFET for 5.5 ms during startup to establish the correct working conditions for transformers and capacitors.

#### Protections

FAN6756AHL provides protection functions including Overload / Open-Loop Protection (OLP),  $V_{DD}$  Over-Voltage Protection (OVP), and Over-Temperature Protection (OTP). OLP, OVP, and OTP are all implemented as Latch Mode protections.

When a Latch Mode protection is triggered, PWM switching is terminated and the MOSFET remains off, causing  $V_{DD}$  to drop. When  $V_{DD}$  drops to the  $V_{DD-OLP}$  (7 V), the internal startup circuit is enabled without resetting the protection and the supply current drawn from HV pin charges the hold-up capacitor. Since the protection is not reset, the IC does not resume PWM switching even when  $V_{DD}$  reaches the turn-on voltage of 17 V, disabling HV startup circuit. Then  $V_{DD}$  drops again down to 7 V. In this manner, the Latch Mode protection alternately charges and discharges  $V_{DD}$  until there is no more energy delivered into HV pin. The protection is reset when  $V_{DD}$  drops to 4 V, which is allowed only after power supply is unplugged from the AC line.

### V<sub>DD</sub> Over-Voltage Protection (OVP)

V<sub>DD</sub> over-voltage protection prevents IC damage caused by voltage exceeding the IC voltage rating. When the V<sub>DD</sub> voltage exceeds 24.5 V, the protection is triggered. This protection is typically caused by an open circuit in the secondary-side feedback network.

### Over-Temperature Protection (OTP) and External Latch Triggering

The RT pin provides adjustable Over-Temperature Protection (OTP) and an external latch triggering function. For OTP; an NTC thermistor, R<sub>NTC</sub>, usually in series with a resistor R<sub>A</sub>, is connected between the RT pin and ground. The internal current source, I<sub>RT</sub> (100 μA), introduces voltage on RT as:

$$V_{RT} = I_{RT} \cdot (R_{NTC} + R_A) \quad (5)$$

At high ambient temperature, R<sub>NTC</sub> decreases, reducing V<sub>RT</sub>. When V<sub>RT</sub> is lower than V<sub>RTTH1</sub> (1.035 V) for longer than t<sub>D-OTP1</sub> (14.5 ms), the protection is triggered and FAN6756AHL enters Latch Mode protection.

The OTP can be triggered by pulling down the RT pin voltage using an opto-coupler or transistor. Once V<sub>RT</sub> is less than V<sub>RTTH2</sub> (0.7 V) for longer than t<sub>D-OTP2</sub> (185 μs), the protection is triggered and FAN6756AHL enters Latch Mode protection.

When OTP is not used, it is recommended to place a 100 kΩ resistor between this pin and ground to prevent noise interference.

### Open-Loop / Overload Protection (OLP)

Because of the pulse-by-pulse current-limit capability, the maximum peak current is limited, and the maximum input power is also limited. If the output consumes more than this limited maximum power, the output voltage (V<sub>O</sub>) drops below the set voltage. Then, the currents through the opto-coupler and transistor become virtually zero and V<sub>FB</sub> is pulled HIGH. Once V<sub>FB</sub> is higher than V<sub>FB-OLP</sub> (4.6 V) for longer than t<sub>D-OLP</sub> (43.5 ms), OLP is triggered. OLP is also triggered when the feedback loop is open by soldering defect.

### Over-Current Protection (OCP)

In addition to the cycle-by-cycle current limiting, the FAN6756AHL defines a lower threshold voltage, V<sub>OCP</sub>, to provide Over-Current Protection (OCP) for applications with surge output current. As shown in Figure 37, OCP is triggered if V<sub>SENSE</sub> exceeds V<sub>OCP</sub> pulse-by-pulse for a period of time (t<sub>D-OLP</sub>). In contrast; if the peak of V<sub>SENSE</sub> is lower than V<sub>OCP</sub> or the over-current lasts less than t<sub>D-OLP</sub>, normal operation continues. The V<sub>OCP</sub> level is adjustable by R<sub>HV</sub> resistors to maintain a constant OCP level.

$$V_{OCP} = \frac{V_{OCP,L} - V_{OCP,H}}{2} \cdot \frac{R_{LS}}{R_{HV}} \cdot V_{LINE}^{PK} + \frac{3 \cdot V_{OCP,L} - V_{OCP,H}}{2} \quad (6)$$

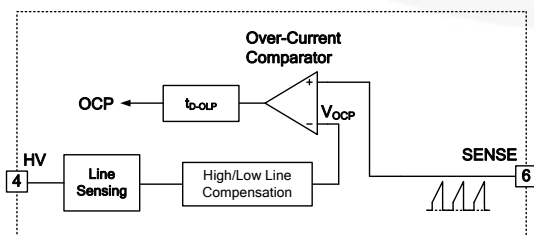


Figure 37. Over-Current Protection Circuit

Figure 38 shows how V<sub>OCP</sub> changes with the line voltage with different R<sub>HV</sub> resistors.

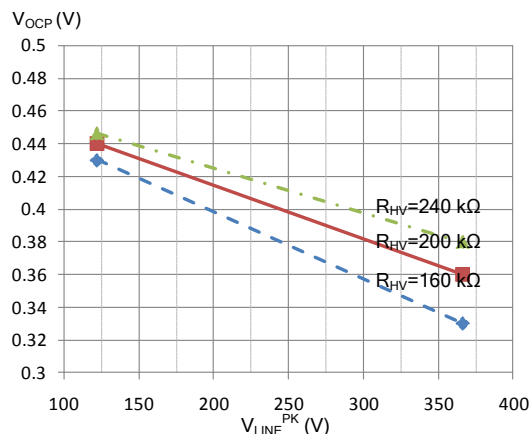


Figure 38. V<sub>OCP</sub> vs. Line Voltage

### Two-Level Under-Voltage Lockout (UVLO)

As shown in Figure 39, as long as protection is not triggered, the turn-off threshold of V<sub>DD</sub> is fixed internally at V<sub>UVLO</sub> (6.5 V). When a protection is triggered, the V<sub>DD</sub> level to terminate PWM gate switching is changed to V<sub>DD-OFF</sub> (11 V), as shown in Figure 40. When V<sub>DD</sub> drops below V<sub>DD-OFF</sub>, the switching is terminated and the operating current from V<sub>DD</sub> is reduced to I<sub>DD-OLP</sub> to slow down the discharge of V<sub>DD</sub> until V<sub>DD</sub> reaches V<sub>DD-OLP</sub>. This delays re-startup after shutdown by protection to minimize the input power and voltage / current stress on the switching devices during a fault condition.

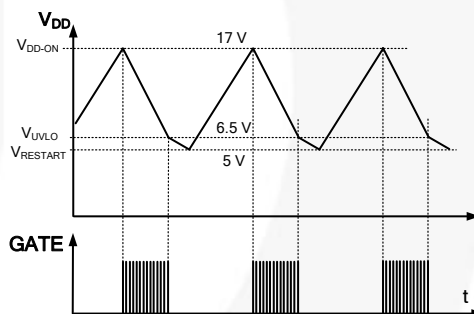


Figure 39. V<sub>DD</sub> UVLO at Normal Mode

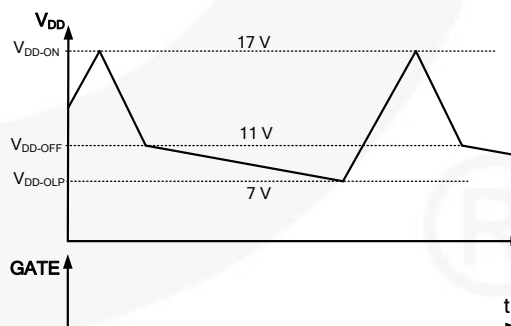
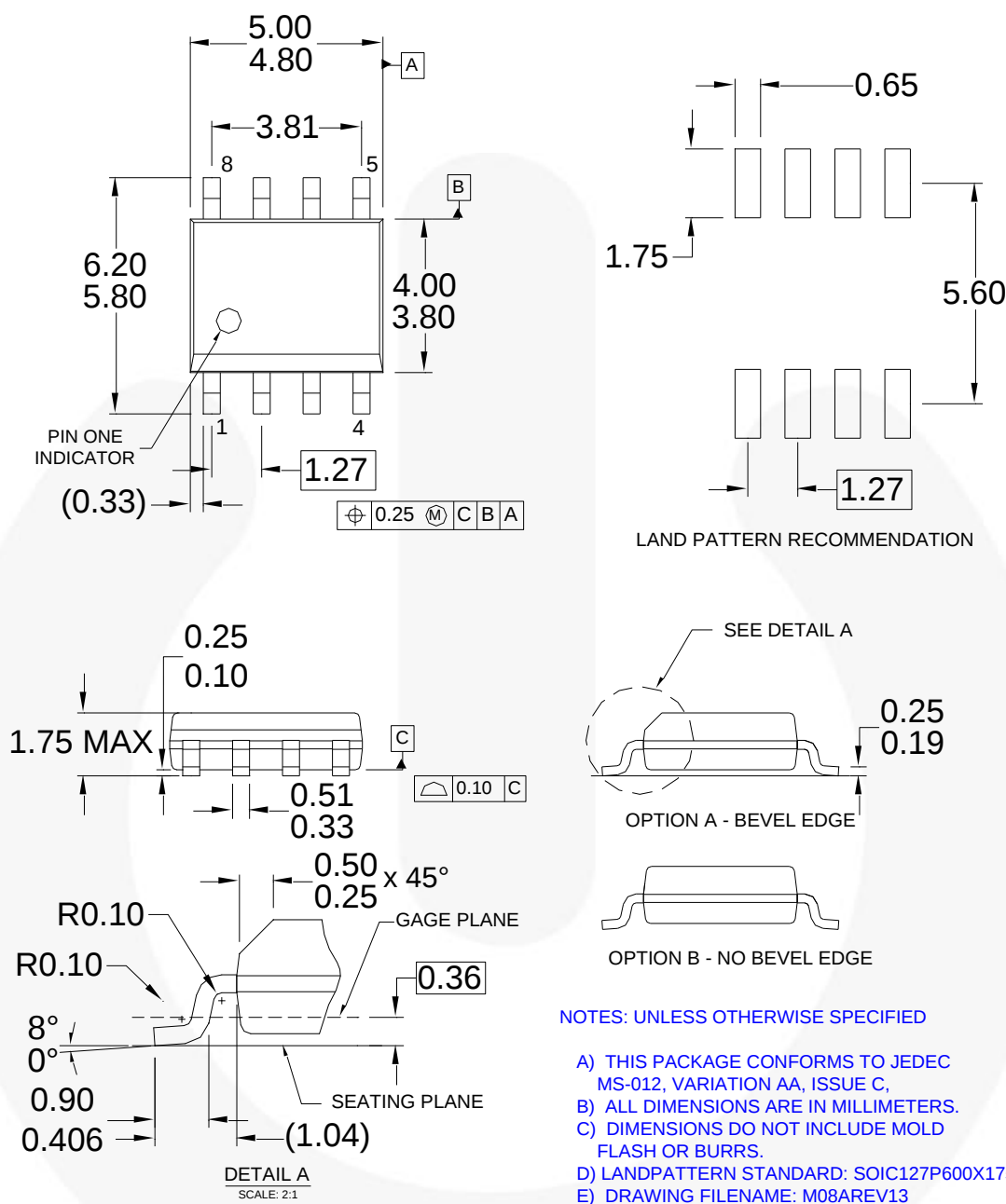


Figure 40. V<sub>DD</sub> UVLO at Protection Mode

### Gate Output / Soft Driving

The BiCMOS output stage has a fast totem-pole gate driver. The output driver is clamped by an internal 14.5 V Zener diode to protect the power MOSFET gate from over voltage. Soft driving is implemented to minimize Electromagnetic Interference (EMI) by reducing the switching noise.

## Physical Dimensions



### Figure 41. 8-Pin SOP-8 Package

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| Build it Now™                                                                     | GreenBridge™                                   | Programmable Active Droop™                                                        | TinyCalc™                                                                           |
| CorePLUS™                                                                         | Green FPS™                                     | QFET®                                                                             | TinyLogic®                                                                          |
| CorePOWER™                                                                        | Green FPS™ e-Series™                           | QS™                                                                               | TINYOPTO™                                                                           |
| CROSSVOLT™                                                                        | Gmax™                                          | Quiet Series™                                                                     | TinyPower™                                                                          |
| CTL™                                                                              | GTO™                                           | RapidConfigure™                                                                   | TinyPWM™                                                                            |
| Current Transfer Logic™                                                           | IntelliMAX™                                    |  | TinyWire™                                                                           |
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| FACT®                                                                             | mWSaver™                                       | SuperSOT™-6                                                                       | VisualMax™                                                                          |
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As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

## ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, [www.fairchildsemi.com](http://www.fairchildsemi.com), under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

## PRODUCT STATUS DEFINITIONS

### Definition of Terms

| Datasheet Identification | Product Status        | Definition                                                                                                                                                                                          |
|--------------------------|-----------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Advance Information      | Formative / In Design | Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.                                                                       |
| Preliminary              | First Production      | Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design. |
| No Identification Needed | Full Production       | Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.                                               |
| Obsolete                 | Not In Production     | Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.                                                    |

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